## **CLAIMS**

1. An Ag sputtering target,

wherein the Ag sputtering target has three-dimensional fluctuation of grain sizes not more than 18%; and

wherein the three-dimensional fluctuation of the grain sizes measured by:

exposing a plurality of sputtering surfaces by slicing the Ag sputtering target in planes parallel to a sputtering starting surface,

selecting a plurality of locations on each of the exposed sputtering surfaces, and

measuring grain sizes D at all the selected locations of all the exposed sputtering surfaces by executing i) to iv) below,

- i) taking an optical micrograph of the selected location,
- ii) drawing a plurality of straight lines equal to or more than four in a grid pattern on the obtained micrograph,
- iii) investigating a number n of grain boundaries on each of the straight lines, and calculating a grain size d (unit:  $\mu$ m) for each of the straight lines on the basis of the following formula:

$$d=L/(n \cdot m)$$

wherein

10

15

L: length of the straight line,

n: number of the grain boundaries on the straight line,

m: magnification of the optical micrograph, and

iv) calculating the grain size D at the selected location as an average value of the grain sizes d for the plurality of straight lines;

calculating values A1 and B1 using the formula below and based on the results of measurement of the grain sizes D at all the selected locations of all the exposed sputtering surfaces:

$$A1 = (D_{\text{max}} - D_{\text{ave}}) / D_{\text{ave}} \times 100$$
 (%)

5 B1 =  $(D_{ave}-D_{min})/D_{ave}\times 100$  (%)

wherein

 $D_{\text{max}}$ : maximum value among the grain sizes D at all the selected locations

 $D_{min}$ : minimum value among the grain sizes D at all the selected locations

D<sub>ave</sub>: average value of the grain sizes D at all the selected locations; and

selecting larger one of the values A1 and B1 as the three-dimensional fluctuation of the grain sizes.

15

- 2. The Ag sputtering target according to claim 1, wherein the average grain size  $D_{ave}$  is not more than 100  $\mu m$ , and the maximum grain size  $D_{max}$  is not more than 120 $\mu m$ .
- 20 3. An Ag sputtering target,

wherein the Ag sputtering target has three-dimensional fluctuation of X-ray diffraction peak intensity ratios  $(X_2/X_1)$  not more than 35%; and

wherein the three-dimensional fluctuation of the X-ray diffraction peak intensity ratios  $(X_2/X_1)$  is measured by:

exposing a plurality of sputtering surfaces by slicing the Ag sputtering target in planes parallel to a sputtering starting surface;

selecting a plurality of locations on each of the exposed sputtering surfaces;

5 measuring the X-ray diffraction peak intensities of the Ag at all the selected locations of all the exposed sputtering surfaces;

calculating the X-ray diffraction peak intensity ratio  $(X_2/X_2)$  for each of the selected locations, the X-ray diffraction peak intensity ratio  $(X_2/X_2)$  being defined as the ratio of the largest Ag X-ray diffraction peak intensity  $X_1$  in relation to the second largest Ag X-ray diffraction peak intensity  $X_2$ ;

calculating values A2 and B2 using the formula below and based on the X-ray diffraction peak intensity ratios  $(X_2/X_1)$  at all the selected locations of all the exposed sputtering surfaces,

wherein

10

25

 $R_{max}$ : maximum value among the X-ray diffraction peak intensity ratios ( $X_2/X_1$ ) at all selected locations

20  $R_{min}$ : minimum value among the X-ray diffraction peak intensity ratios  $(X_2/X_1)$  at all selected locations

 $R_{ave}$ : average value of the X-ray diffraction peak intensity ratios  $(X_2/X_1)$  at all selected locations; and

selecting the larger one of the values A2 and B2 as the three-dimensional fluctuation of the X-ray diffraction peak intensity

ratio  $(X_2/X_1)$ .

4. An Ag sputtering target according to any one of claims 1 to 3, having a disc-like shape.

5

20

- 5. An Ag sputtering target according to any one of claims 1 to 4, formed by Ag alloy containing rare-earth metal.
- 6. An Ag sputtering target according to claim 5, wherein a content10 of the rare-earth meal is not more than 5 atomic percent (not including 0 atomic percent).
  - 7. A method for producing the Ag sputtering target according to any of claims 1 to 6, comprising:
- conducting a cold forging operation one or more times, the cold forging operation comprising,

solid forging an Ag columnar mass so as to be extended in a axial direction thereof, and

cold upsetting the solid forged Ag columnar mass in the axial direction while maintaining a columnar shape of the solid forged Ag columnar mass; and

slicing a cold-worked columnar mass obtained by the cold forging operation in rounds after being heat treatment.

25 8. A method for producing an Ag thin film, compriing:

forming the Ag thin film on a substrate by sputtering using the Ag sputtering target according to any one of claims 1 to 6.